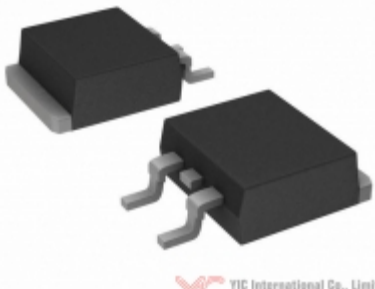






	<h2 style="color: red;">IPB120N04S3-02</h2>	
	Hersteller-Teilenummer:	IPB120N04S3-02
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	MOSFET N-CH 40V 120A TO263-3
Datenblätter:	 IPB120N04S3-02.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 37383 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	IPB120N04S3-02
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 40V 120A TO263-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	37383 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	PG-TO263-2
Verlustleistung (max)	300W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	120A (Tc)
Rds On (Max) @ Id, Vgs	2 mOhm @ 80A, 10V
VGS (th) (Max) @ Id	4V @ 230µA
Gate Charge (Qg) (Max) @ Vgs	210nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	14300pF @ 25V
Verpackung	Tape & Reel (TR)

IPB120N04S3-02 ist neu im Original, Suche IPB120N04S3-02 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPB120N04S3-02 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPB120N04S3-02: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IPB120N04S402ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 40V 120A TO263-3-2</p>	 <p>IPB11N60S5 International Rectifier (Infineon Technologies) IPB11N60S5 INFINEON</p>	 <p>IPB120N03S4L03ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH TO263-3</p>	 <p>IPB11N03LA G International Rectifier (Infineon Technologies) MOSFET N-CH 25V 30A D2PAK</p>
 <p>IPB120N04S401ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 40V 120A TO263-3-2</p>	 <p>IPB120N04S4-01 INF IPB120N04S4-01 INF</p>	 <p>IPB120N04S4-02(4N0402) INFINEO IPB120N04S4-02(4N0402) INFINEO</p>	 <p>IPB11N03LAG VB IPB11N03LAG VB</p>

heiße Teile

Mehr

- | | | | | |
|-------------------|-------------------|-------------------|-------------------|-------------------|
| ⊗ IPB100N04S3 | ↔ IPB100N04S3-03 | ⇒ IPB100N04S3-03M | D IPB100N04S4-02D | ↔ IPB100N04S4-03D |
| ⊣ IPB100N04S4-H2 | ⊗ IPB100N06S2-05 | D IPB100N06S2L-05 | ⇒ IPB100N06S3-03 | ↔ IPB100N06S3-04 |
| ⊗ IPB100N06S3L-03 | ⊣ IPB100N06S3L-04 | ⊗ IPB100N08S2-07 | ↔ IPB100N08S2L-07 | ↔ IPB100N10S3-05 |
| D IPB107N20N3G | ⊗ IPB10N03L | ⊣ IPB10N03LB | ⊗ IPB10N03LBG | ↔ IPB110N06L |
| ⇒ IPB110N06LG | ↔ IPB114N03L | ⊗ IPB114N03LG | ⊣ IPB11N03LAG | ↔ IPB11N60S5 |
| ↔ IPB120N04S4-01 | ⇒ IPB120N04S4-02 | D IPB120N06NG | ⊗ IPB120N06S4 | ⊣ IPB120N06S4-02 |
| ⊗ IPB120N06S4-03 | D IPB120N06S4-H1 | ⇒ IPB120P04L03 | ↔ IPB120P04P4L-03 | ↔ IPB123N10N3 |
| ⊣ IPB123N10N3G | ⊗ IPB12CN10LG | ↔ IPB12CN10NG | ⇒ IPB12CNE8NG | ↔ IPB136N08N3 |
| ⊗ IPB136N08N3G | ⊣ IPB13N03LBG | ⊗ IPB144N12N3 | D IPB144N12N3G | ↔ IPB147N03L |
| ↔ IPB147N03LG | ⊗ IPB14N03LA | ⊣ IPB14N03LAG | ⊗ IPB14N03LAP | ↔ IPB14N03LAT |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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